

Preliminar notes on maximum-flow problem solved in FCPP.

Notation:

- G will denote the directed weighted graph of capacities, s and t will denote respectively source and sink of our graph.
- We will assume that capacities are nonnegative and symmetrical.
- For a path \mathbf{p} we will denote with $|\mathbf{p}|$ its lenght.

When it will be convenient, we will treat a directed weighted graph G as a function $G : V \times V \rightarrow \mathbb{R}_+$, where V is its set of vertices. With a little abuse of notation we will say that the edge from a node δ to a node δ' is in G , or $(\delta, \delta') \in G$, in place of $G(\delta, \delta') \neq 0$.

Likewise we will say that a path \mathbf{p} is contained in G , or $\mathbf{p} \subset G$, if every edge

- For a field Φ , \mathcal{R}_Φ will denote the directed weighted graph of residual capacities respect to Φ :

$$\mathcal{R} = G - \Phi \quad (1)$$

- We define admissible path respect to Φ a path γ in G from source to sink such that

$$\Phi|_\gamma < G|_\gamma$$

- We say that a flow Φ is maximal if there are no admissible paths in G respect to Φ .

Proposizione 0.1. Φ is a maximum flow iff \mathcal{R}_Φ does not have paths from source to sink.

For a field-value f in δ we define $|f| := \sum_{\delta \sim \delta'} f(\delta')$. We now formalize functions involved in the algorithm.
We define $\Phi^*(\delta, \delta') := \Phi(\delta', \delta)$.

Definition 1. Let Φ be a field with values in \mathbb{R} and let d be a locally constant field d with values in $\mathbb{N} \cup \{\infty\}$. We say that the couple (Φ, d) is admissible for G if, for all devices $\delta \sim \delta'$, the following are satisfied:

- (i) $\Phi(\delta, \delta) = 0 \wedge -G \leq \Phi \leq G \wedge (\Phi < 0 \rightarrow \Phi^* \geq 0)$;
- (ii) $d(t) = 0$;
- (iii) $(d(\delta') < \infty \wedge d(\delta) = d(\delta') + 1) \rightarrow (\Phi(\delta, \delta') < G(\delta, \delta'))$.

Example 1. For a flow Φ , $(\Phi, \text{dist}_{\mathcal{R}_\Phi}(\cdot, t))$ is admissible.

Example 2. $(0, \delta \neq t \mapsto \infty)$ is admissible.

Example 3. Let (Φ, d) be admissible for G . If H is a subgraph of G then $(\Phi|_H, d|_H)$ is admissible for H .

Example 4. Let (Φ, d) be admissible for G . If H is a supergraph of G then (Φ_H, d_H) is admissible for H , where Φ_H is the extension of Φ with default 0 and d_H is the extension of d with default ∞ .

Proposizione 0.2. Let G and G' be two graphs on the set of devices. Suppose that G and G' are compatible, i.e. for all devices δ, δ' one has $(G \neq 0 \wedge G' \neq 0) \rightarrow (G = G')$.

If (Φ, d) is an admissible couple for G , then $((\Phi|_{G \cap G'})_{G'}, (\Phi|_{G \cap G'})_{G'})$ is compatible for G' .

Proof. (SKETCH) It's a consequence of the two previous examples. \square

Definition 2. Given an admissible couple (Φ, d) for G , we define by co-induction:

$$\begin{aligned} \Phi_0 &:= \Phi \\ \mathcal{R}_n &:= \mathcal{R}_{\Phi_n} \\ e_n(\delta) &:= \begin{cases} \infty & \text{if } \delta = s \\ -\infty & \text{if } \delta = t \\ |\Phi_n(\delta)| & \text{otherwise} \end{cases} \\ d_0 &:= d \\ d_n(\delta) &:= \begin{cases} 0 & \text{if } \delta = t \\ \min\{d_{n-1}(\delta') + 1 \mid \mathcal{R}_{n-1}(\delta, \delta') > 0\} & \text{otherwise} \end{cases} \\ I_n &:= \text{trunc}((G + \Phi_{n-1}^*) \cdot (d_{n-1}^* < d_n), e(\Phi_{n-1}^*)) \\ \Phi_n &:= -\Phi_{n-1}^* + I_n + \text{trunc}(\Phi_{n-1}^*, e(\Phi_{n-1}^* - I_n)) \\ X_n &:= \{\delta \mid d_n(\delta) = \infty\} \end{aligned}$$

Lemma 0.3. Eventually $\{X_n\}_n$ stabilizes to a set of devices X .

Proof. For every $n \in \mathbb{N}$ let's consider the set $T_n = \{\delta \mid \text{dist}_G(\delta, t) \leq n\}$.

We prove by induction that for $\delta \notin T_n$ we have $d_n(\delta) = \infty$.

Base step: $T_0 = \{t\}$, and condition on d_0 holds by definition.

Inductive step: suppose that $\forall \delta' \notin T_{n-1} \ d_{n-1}(\delta') = \infty$ and consider a $\delta \notin T_n$.

We have $d_n(\delta) = \min\{d_{n-1}(\delta') + 1 \mid \mathcal{R}_{n-1}(\delta, \delta') > 0\}$ and since no $\delta' \sim \delta$ is in T_{n-1} , condition on d_n holds by inductive hypothesis.

As a consequence, for a $\delta \in T_n$

$$d_n(\delta) = \min_{\delta' \in T_{n-1}} \{d_{n-1}(\delta') + 1 \mid \mathcal{R}_{n-1}(\delta, \delta') > 0\}$$

Now we want to show by induction that $\forall n \ X_n \cap T_n \subseteq X_{n+1} \cap T_{n+1}$.

Base step: $X_0 \cap T_0 = \emptyset$ and we have done.

Inductive step: let δ be a device in $X_n \cap T_n$ and $\delta' \in T_{n-1}$ such that $\delta' \sim \delta$.

We have $d_{n-1}(\delta') = \infty \vee \mathcal{R}_{n-1}(\delta, \delta') = 0$. If $d_{n-1}(\delta') = \infty$ then $d_n(\delta') = \infty$ by inductive hypothesis. Otherwise let's suppose $d_{n-1}(\delta') < \infty$, $\mathcal{R}_{n-1}(\delta, \delta') = 0$ and $d_n(\delta') < \infty$. In this case $e(I_n(\delta')) = e(\Phi_{n-1}^*(\delta'))$, i.e.

$$\forall \delta' \sim \delta \quad \mathcal{R}_{n-1}(\delta, \delta') \cdot (d_{n-1}(\delta') < d_n(\delta)) = 0$$

and thus $I_n(\delta)$ is a zero field-value. So we have

□